

RoHS Compliant Product

A suffix of "C" specifies halogen free

FEATURES

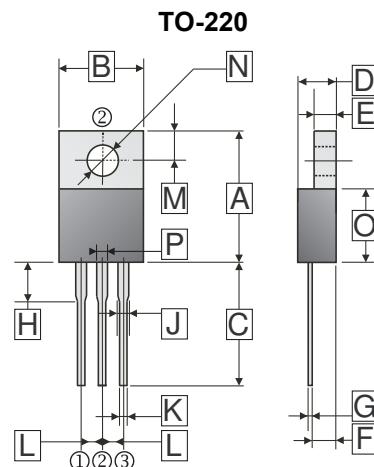
- Planar MOS Schottky technology
- Low forward voltage drop
- High current capability
- High reliability
- High surge current capability
- Epitaxial construction

MECHANICAL DATA

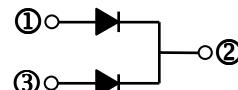
- Case: Molded plastic
- Epoxy: UL94V-0 rate flame retardant
- Lead: Lead solderable per MIL-STD-202 method 208 guaranteed
- Polarity: As Marked
- Mounting position: Any

ORDER INFORMATION

Part Number	Type
SBL10U45	Lead (Pb)-free
SBL10U45-C	Lead (Pb)-free and Halogen-free



REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	14.22	16.51	J	0.70	1.78
B	9.57	10.90	K	0.38	1.11
C	12.50	14.75	L	2.01	3.07
D	3.56	5.10	M	2.22	3.43
E	0.51	1.47	N	3.10	4.31
F	2.03	3.19	O	8.10	9.65
G	0.279	0.76	P	1.18	Typ.
H	2.95	4.5			



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Rating 25°C ambient temperature unless otherwise specified. Single phase half wave, 60Hz, resistive or inductive load.)

For capacitive load, de-rate current by 20%.)

Parameter	Symbol	Rating	Unit
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	45	V
Working Peak Reverse Voltage	V_{RSM}	45	V
Maximum DC Blocking Voltage	V_{DC}	45	V
Maximum Average Forward Rectified Current (Per Leg) (Per Device)	I_F	5	A
		10	
Peak Forward Surge Current, 8.3 ms single half sine-wave Superimposed on rated load (JEDEC method)	I_{FSM}	120	A
Voltage Rate of Change (Rated V_R)	dv/dt	10000	V / μ s
Typical Thermal Resistance	$R_{\theta JC}$	2	$^{\circ}\text{C} / \text{W}$
Operating and Storage Temperature Range	T_J, T_{STG}	-40~150	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS

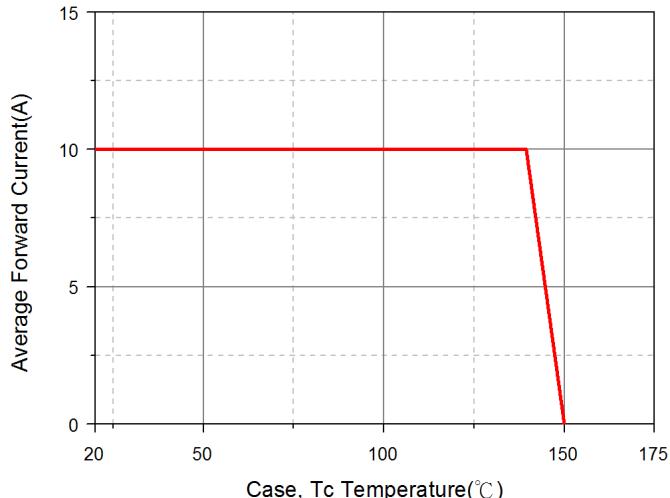
Parameter	Symbol	Typ.	Max.	Unit	Test Condition
Maximum Instantaneous Forward Voltage	V_F	0.38	-	V	$I_F=3\text{A}, T_J=25^{\circ}\text{C}$
		0.42	0.48		$I_F=5\text{A}, T_J=25^{\circ}\text{C}$
		0.31	-		$I_F=3\text{A}, T_J=125^{\circ}\text{C}$
		0.38	-		$I_F=5\text{A}, T_J=125^{\circ}\text{C}$
Maximum DC Reverse Current at Rated DC Blocking Voltage ²	I_R	-	0.5	mA	$T_J=25^{\circ}\text{C}$
		-	20		$T_J=100^{\circ}\text{C}$
Typical Junction Capacitance ¹	C_J	320	-	pF	

Notes:

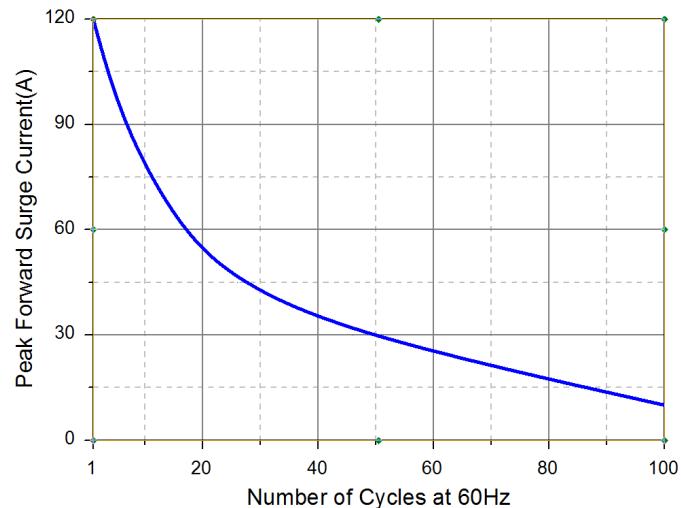
1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
2. Pulse Test : Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

RATING AND CHARACTERISTIC CURVES

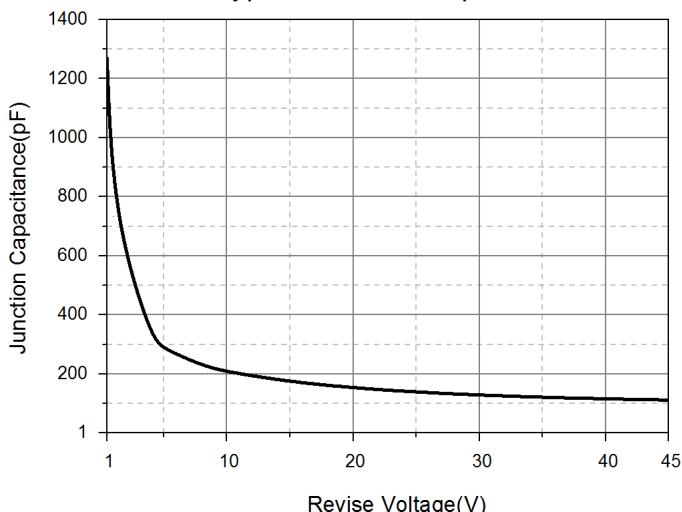
Typical Forward Current Derating Curve



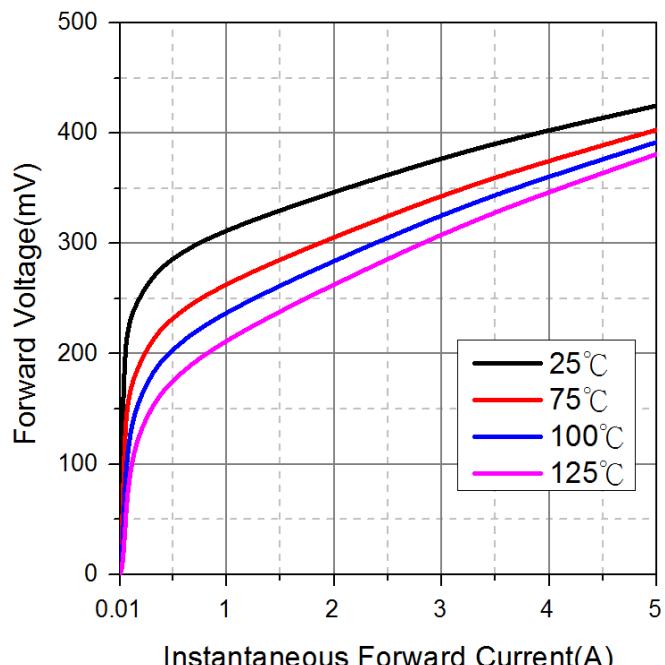
Maximum Non-Repetitive Forward Surge Current



Typical Junction Capacitance



Typical Forward Characteristic



Typical Reverse Characteristic

